

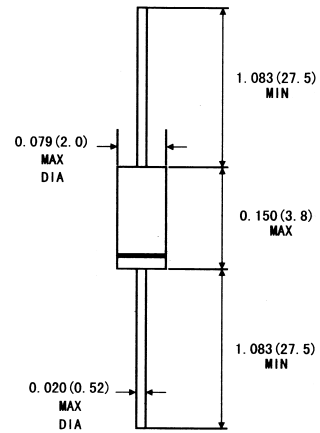
FEATURES

- . The zener voltage are gaded accrding to the intermational E24 standard. Over voltage tolerance and higher zener voltage on request

MECHANICAL DATA

- . **Case:** DO-35 glass case
- . **Polarity:** Color band denotes cathode end
- . **weight:** Approx. 0.13 gram

DO-35



Dimensions in inches and (millimeters)

ABSOLUTE MAXIMUM RATINGS(LIMITING VALUES)(TA=25°C)

	Symbols	Value	Units
Zener current see table "Characteristics"			
Power dissipation at TA=25°C	P _{tot}	500 ¹⁾	mW
Junction temperature	T _J	175	°C
Storage temperature range	T _{STG}	-55 to +175	°C

1)Valid provided that a distance of 8mm from case are kept at ambient temperature

ELECTRCAL CHARACTERISTICS(TA=25°C)

	Symbols	Min	Typ	Max	Units
Thermal resistance junction to ambient	R _θ			300 ¹⁾	K/W

1) Valid provided that a distance at 8mm from case are kept at ambient temperature

ZPD2.7 THRU ZPD51 SILICON PLANAR ZENER DIODES

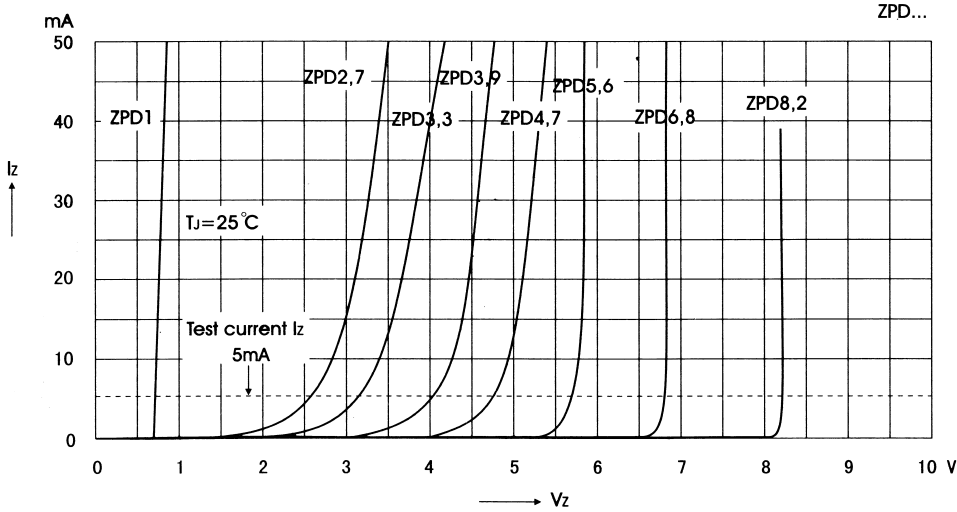
Type	Zener Voltage range 1)		Dynamic resistance			Temp. Coeff. of Zener Volt at I _z =5mA	Reverse Voltage at I _r =100nA Min. V _R (V)	Admissible Zener Current of			
	V _{znom}	I _{ZT} for V _{ZT} 2)		r _{zjt} and r _{zjk} at I _{ZK}				T _{amb} = 45 °C	T _{amb} = 25 °C		
		v	mA	V	Ω			Ω	mA	I _{zmA}	I _{zmA}
ZPD2.7	2.7	5	2.5..2.9	<83	<50	1	-9...-4	0.8	135	160	
ZPD3	3.0		2.8..3.2	<95	<500		-9...-3		117	140	
ZPD3.3	3.3		3.1..3.5				-8...-3		109	130	
ZPD3.6	3.6		3.4..3.8				-8...-3		101	120	
ZPD3.9	3.9		3.7..4.1				-7...-3		92	110	
ZPD4.3	4.3		4.0..4.6				-6...-1		85	100	
ZPD4.7	4.7		4.4..5.0				<78		-5...+2	76	90
ZPD5.1	5.1		4.8..5.4				<60	<480	-3...+4	67	80
ZPD5.6	5.6		5.2..6.0	<40	<400		-2...+6	1	59	70	
ZPD6.2	6.2		5.8..6.6	<10	<200		-1...+7	2	54	64	
ZPD6.8	6.8		6.4..7.2	<8	<150		+2...+7	3	49	58	
ZPD7.5	7.5		7.0..7.9	<7	<50		+3...+7	5	44	53	
ZPD8.2	8.2		7.7..8.7	<7			+4...+7	6	40	47	
ZPD9.1	9.1		8.5..9.6	<10	<250		+5...+8	7	36	43	
ZPD10	10		9.4..10.6	<15			<70	+5...+8	7.5	33	40
ZPD11	11		10.4..11.6	<20			<70	+5...+9	8.5	30	36
ZPD12	12		11.4..12.7	<20			<90	+6...+9	9	28	32
ZPD13	13		12.4..14.1	<25			<110	+7...+9	10	25	29
ZPD15	15		13.8..15.6	<30			<110	+7...+9	11	23	27
ZPD16	16		15.3..17.1	<40			<170	+8...+9.5	12	20	24
ZPD18	18	16.8..19.1	<50	<170		+8...+9.5	13	18	21		
ZPD20	20	18.8..21.2	<50	<220		+8...+10	15	17	20		
ZPD22	22	20.8..23.3	<55			+8...+10	16	16	18		
ZPD24	24	22.8..25.6	<80	<250	+8...+10	18	13	16			
ZPD27	27	25.1..28.9			+8...+10	20	12	14			
ZPD30	30	28..32			+8...+10	22.5	10	13			
ZPD33	33	31..35			+8...+10	25	9	12			
ZPD36	36	34..38			<90	+8...+10	27	9	11		
ZPD39	39	37..41	<90	<300	+10...+12	29	8	10			
ZPD43	43	40..46	<100	<700	+10...+12	32	7	9.2			
ZPD47	47	44..50	<100	<750	+10...+12	35	6	8.5			
ZPD51	51	48..54	<100	<750	+10...+12	38	6	7.8			

NOTE 1) TESTED WITH PULSE T_p=20mS

2) Valid provided that electrodes are kept ambient temperature at a distance of 8mm from case

ZPD2.7 THRU ZPD51 SILICON PLANAR POWER ZENER DIODES

BREAKDOWN CHARACTERISTICS AT $T_J=CONSTANT$ (PULSED)



BREAKDOWN CHARACTERISTICS AT $T_J=CONSTANT$ (PULSED)

